

DESCRIPTION

The AO1378 amplifier is a new generation of zero-drift, micro-power, CMOS operational amplifiers, the AO1378 offer bandwidth of 1.8MHz, rail-to-rail inputs and outputs, and single-supply operation from 1.8V to 5.5V. The Combination of low input voltage noise, high gain bandwidth (1.8MHz) and low power (180µA) enable AO1378 to achieve optimum performance for low-power precision applications.

The AO1378 uses chopper stabilized technique to provide very low offset voltage (less than $5\mu V$ maximum) and near zero drift over temperature. Low quiescent supply current of $180\mu A$ per amplifier and very low input bias current of 20pA make the devices an ideal choice for low offset, low power consumption and high impedance applications. The AO1378 offers excellent CMRR without the crossover associated with traditional complementary input stages. This design results in superior performance for driving analog-to-digital converters (ADCs) without degradation of differential linearity.

The AO1378 is available in SOT-25 and SOP8 packages.

ORDERING INFORMATION

Package Type	Part Number		
SOT-25	F.5	AO1378E5R	
SPQ: 3,000pcs/Reel	E5	AO1378E5VR	
SOP8	MO	AO1378M8R	
SPQ: 4,000pcs/Reel	M8	AO1378M8VR	
Note	V: Halogen free Package		
Note	R: Tape & Reel		
AiT provides all RoHS products			

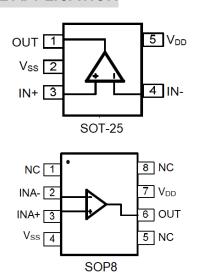
FEATURES

- Single-Supply Operation from +1.8V ~ +5.5V
- Rail-to-Rail Input / Output
- Gain-Bandwidth Product: 1.8MHz (Typ. @25°C)
- Low Input Bias Current: 20pA (Typ. @25°C)
- Low Offset Voltage: 30µV (Max. @25°C)
- Quiescent Current: 180µA per Amplifier (Typ)
- Operating Temperature: -45°C ~ +125°C
- Zero Drift: 0.03µV/°C (Typ)
- Embedded RF Anti-EMI Filter
- Available in SOT-25 and SOP8 packages

APPLICATION

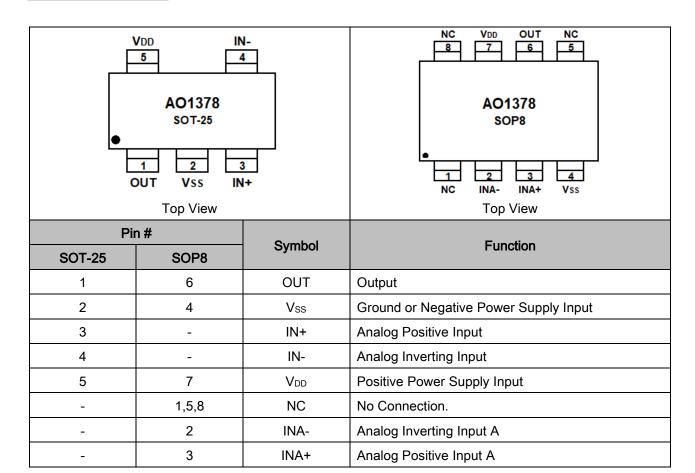
- Portable Medical Devices
 - -Glucose Meters
 - -Oxygen Metering
 - -Heat Rate Monitors
- Weight Scales
- Battery-Powered Instruments
- Thermopile Modules
- Handheld Test Equipment
- Sensor Signal Conditioning
- Transducer Application
- Temperature Measurements

TYPICAL APPLICATION



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PIN DESCRIPTION



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ABSOLUTE MAXIMUM RATINGS

Power Supply Voltage (V _{DD} to V _{SS})	-0.5V ~ +7.5V			
Analog Input Voltage (IN+ or IN-)	$Vss-0.5V \sim V_{DD}+0.5V$			
PDB Input Voltage	Vss-0.5V ~ +7V			
Operating Temperature Range	-45°C ~ 125°C			
Junction Temperature	+160°C			
Storage Temperature Range	-55°C ~ 150°C			
Lead Temperature (soldering, 10sec)	+260°C			
Package Thermal Resistance (T _A =+25°C)				
θ _{JA} , SOT-25	190°C/W			
θ _{JA} , SOP8	125°C/W			
ESD Susceptibility				
НВМ	6kV			
MM	400V			

Stress beyond above listed "Absolute Maximum Ratings" may lead permanent damage to the device. These are stress ratings only and operations of the device at these or any other conditions beyond those indicated in the operational sections of the specifications are not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

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ELECTRICAL CHARACTERISTICS

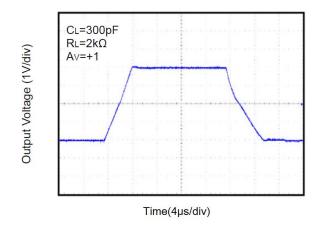
 $V_S = +5V$, $V_{CM} = +2.5V$, $V_O = +2.5V$, $T_A = +25^{\circ}C$, unless otherwise noted.

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
INPUT CHARACTERISTICS						
Input Offset Voltage	Vos		-	1	30	μV
Input Bias Current	lΒ		-	20	ı	pА
Input Offset Current	los		-	10	1	pА
Common-Mode Rejection Ratio	CMRR	V _{CM} = 0V to 5V	-	110	1	dB
Large Signal Voltage Gain	A _{VO}	$R_L = 10k\Omega$, $V_O = 0.3V$ to 4.7V	-	145	ı	dB
Input Offset Voltage Drift	$\Delta V_{OS}/\Delta_T$		-	30	ı	nV/°C
OUTPUT CHARACTERISTICS	3					
Output Voltage High	.,	$R_L = 100k\Omega$ to - V_S	-	4.998	ı	V
	V _{OH}	$R_L = 10k\Omega$ to - V_S	-	4.994	1	
Output Voltage Low	V _{OL}	$R_L = 100k\Omega$ to + V_S	-	2	ı	mV
		$R_L = 10k\Omega$ to + V_S	-	5	-	
Short Circuit Limit	I _{SC}	$R_L = 10\Omega$ to - V_S	-	60	ı	mA
Output Current	lo		-	65	ı	mA
POWER SUPPLY						
Power Supply Rejection Ratio	PSRR	Vs = 2.5V to 5.5V	-	115	1	dB
Quiescent Current	ΙQ	$V_0 = 0V$, $R_L = 0\Omega$	-	180	ı	μA
DYNAMIC PERFORMANCE						
Gain-Bandwidth Product	GBP	G = +100	-	1.8	ı	MHz
Slew Rate	SR	$R_L = 10k\Omega$	-	0.95	ı	V/µs
Overload Recovery Time			-	0.10	ı	ms
NOISE PERFORMANCE						
Voltage Noise	e _n p-p	0Hz to 10Hz	-	0.3	1	μV _{P-P}
Voltage Noise Density	en	f = 1kHz	_	38	-	nV/ √Hz

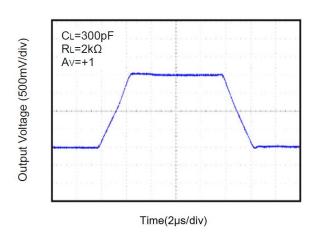
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TYPICAL PERFORMANCE CHARACTERISTICS

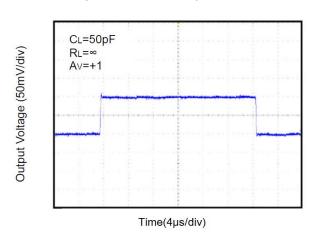
1. Large Signal Transient Response at +5V



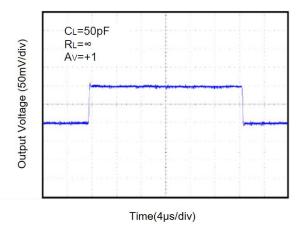
2. Large Signal Transient Response at +2.5V



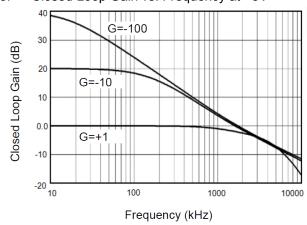
3. Small Signal Transient Response at +5V



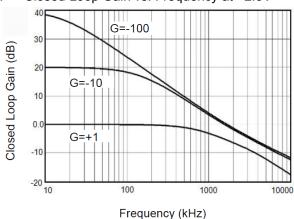
4. Small Signal Transient Response at +2.5V



5. Closed Loop Gain vs. Frequency at +5V



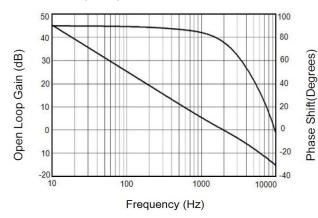
6. Closed Loop Gain vs. Frequency at +2.5V



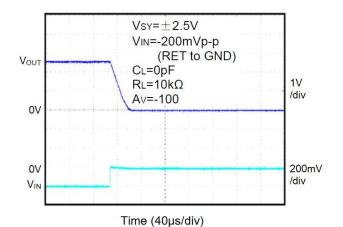
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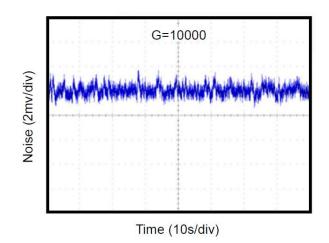




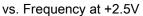
9. Positive Overvoltage Recovery

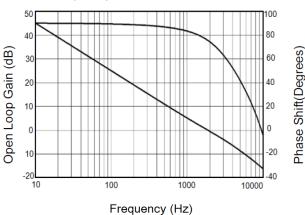


11. 0.1Hz to 10Hz Noise at +5V

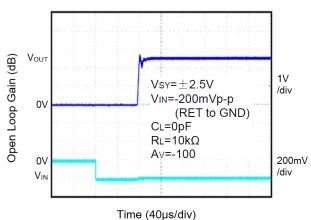


8. Open Loop Gain, Phase Shift

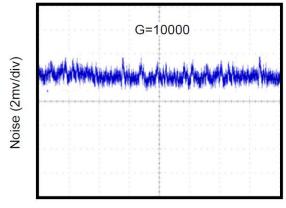




10. Negative Overvoltage Recovery



12. 0.1Hz to 10Hz Noise at +2.5V



Time (10s/div)

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DETAILED INFORMATION

Size

AO1378 op amps are unity-gain stable and suitable for a wide range of general-purpose applications. The small footprints of the AO1378 packages save space on printed circuit boards and enable the design of smaller electronic products.

Power Supply Bypassing and Board Layout

AO1378 operates from a single 1.8V to 5.5V supply or dual ± 0.9 V to ± 2.75 V supplies. For best performance, a 0.1μ F ceramic capacitor should be placed close to the V_{DD} pin in single supply operation. For dual supply operation, both V_{DD} and V_{SS} supplies should be bypassed to ground with separate 0.1μ F ceramic capacitors.

Low Supply Current

The low supply current (typical 180uA per channel) of AO1378 will help to maximize battery life. They are ideal for battery powered systems

Operating Voltage

AO1378 operate under wide input supply voltage (1.8V to 5.5V). In addition, all temperature specifications apply from -40°C to +125°C. Most behavior remains unchanged throughout the full operating voltage range. These guarantees ensure operation throughout the single Li-lon battery lifetime

Rail-to-Rail Input

The input common-mode range of AO1378 extends 100mV beyond the supply rails (V_{SS} -0.1V to V_{DD} +0.1V). This is achieved by using complementary input stage. For normal operation, inputs should be limited to this range.

Rail-to-Rail Output

Rail-to-Rail output swing provides maximum possible dynamic range at the output. This is particularly important when operating in low supply voltages. The output voltage of AO1378 can typically swing to less than 5mV from supply rail in light resistive loads (>100k Ω), and 60mV of supply rail in moderate resistive loads (10k Ω).

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Capacitive Load Tolerance

The AO1378 is optimized for bandwidth and speed, not for driving capacitive loads. Output capacitance will create a pole in the amplifier's feedback path, leading to excessive peaking and potential oscillation. If dealing with load capacitance is a requirement of the application, the two strategies to consider are (1) using a small resistor in series with the amplifier's output and the load capacitance and (2) reducing the bandwidth of the amplifier's feedback loop by increasing the overall noise gain.

Figure 1. shows a unity gain follower using the series resistor strategy. The resistor isolates the output from the capacitance and, more importantly, creates a zero in the feedback path that compensates for the pole created by the output capacitance.

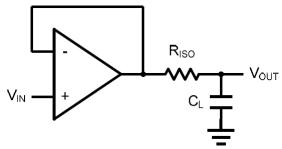


Figure 1. Indirectly Driving a Capacitive Load Using Isolation Resistor

The bigger the $R_{\rm ISO}$ resistor value, the more stable $V_{\rm OUT}$ will be. However, if there is a resistive load $R_{\rm L}$ in parallel with the capacitive load, a voltage divider (proportional to $R_{\rm ISO}/R_{\rm L}$) is formed, this will result in a gain error.

The circuit in Figure 2. is an improvement to the one in Figure 1. R_F provides the DC accuracy by feed-forward the V_{IN} to R_L . C_F and R_{ISO} serve to counteract the loss of phase margin by feeding the high frequency component of the output signal back to the amplifier's inverting input, thereby preserving the phase margin in the overall feedback loop. Capacitive drive can be increased by increasing the value of C_F . This in turn will slow down the pulse response.

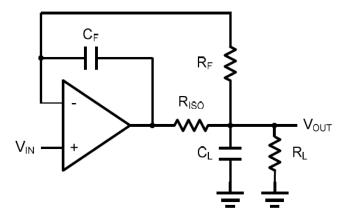


Figure 2. Indirectly Driving a Capacitive Load with DC Accuracy

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Typical Application Circuits

Differential amplifier

The differential amplifier allows the subtraction of two input voltages or cancellation of a signal common the two inputs. It is useful as a computational amplifier in making a differential to single-end conversion or in rejecting a common mode signal. Figure 3. shown the differential amplifier using AO1378.

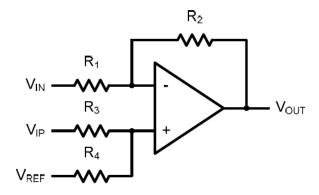


Figure 3. Differential Amplifier

$$V_{OUT} = \left(\frac{R_1 + R_2}{R_3 + R_4}\right) \frac{R_4}{R_1} V_{IN} - \frac{R_2}{R_1} V_{IP} + \left(\frac{R_1 + R_2}{R_3 + R_4}\right) \frac{R_3}{R_1} V_{REF}$$

If the resistor ratios are equal (i.e. $R_1=R_3$ and $R_2=R_4$), then

$$V_{OUT} = \frac{R_2}{R_1} (V_{IP} - V_{IN}) + V_{REF}$$

Low Pass Active Filter

The low pass active filter is shown in Figure 4. The DC gain is defined by $-R_2/R_1$. The filter has a -20dB/decade roll-off after its corner frequency $f_C=1/(2\pi R_3C_1)$.

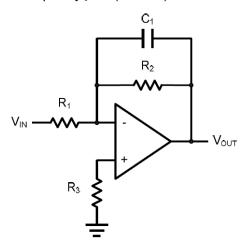


Figure 4. Low Pass Active Filter

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Instrumentation Amplifier

The triple AO1378 can be used to build a three-op-amp instrumentation amplifier as shown in Figure 5. The amplifier in Figure 5 is a high input impedance differential amplifier with gain of R_2/R_1 . The two differential voltage followers assure the high input impedance of the amplifier.

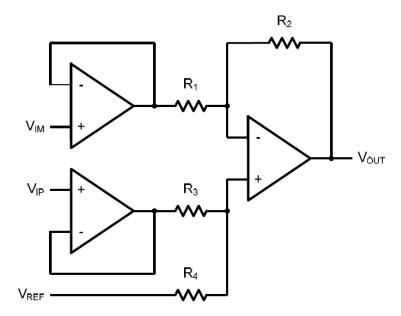


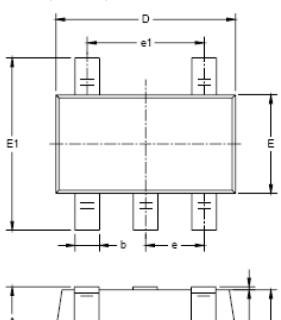
Figure 5. Instrument Amplifier

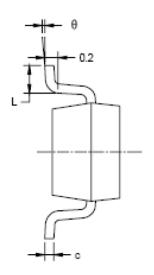
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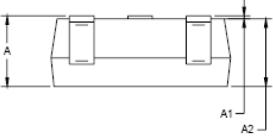


PACKAGE INFORMATION

Dimension in SOT-25 (Unit: mm)



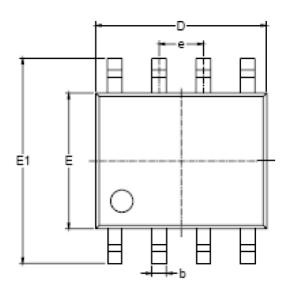


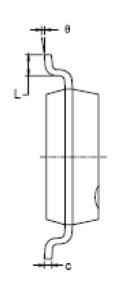


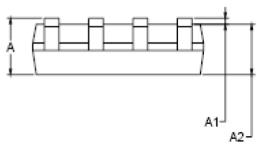
Symbol	Millimeters		Inches		
	Min.	Max.	Min.	Max.	
А	1.050	1.250	0.041	0.049	
A1	0.000	0.100	0.000	0.004	
A2	1.050	1.150	0.041	0.045	
b	0.300	0.500	0.012	0.020	
С	0.100	0.200	0.004	0.008	
D	2.820	3.020	0.111	0.119	
Е	1.500	1.700	0.059	0.067	
E1	2.650	2.950	0.104	0.116	
е	0.950 BSC		0.037	BSC	
e1	1.900 BSC		1 1.900 BSC 0.075 BSC		BSC
L	0.300	0.600	0.012	0.024	
θ	0°	8°	0°	8°	

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Dimension in SOP8 (Unit: mm)







Symbol	Millimeters		Inches		
	Min.	Max.	Min.	Max.	
Α	1.350	1.750	0.053	0.069	
A1	0.100	0.250	0.004	0.010	
A2	1.350	1.550	0.053	0.061	
b	0.330	0.510	0.013	0.020	
С	0.170	0.250	0.006	0.010	
D	4.700	5.100	0.185	0.200	
Е	3.800	4.000	0.150	0.157	
E1	5.800	6.200	0.228	0.244	
е	1.270 BSC		1.270 BSC 0.050 BSC		
L	0.400	1.270	0.016	0.050	
θ	0°	8°	0°	8°	

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